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74HC40103 8-bit synchronous binary down counter Rev. 5 – 21 April 2016

Product data sheet

1. General description

The 74HC40103 is an 8-bit synchronous down counter. It has control inputs for enabling or disabling the clock (CP), for clearing the counter to its maximum count and for presetting the counter either synchronously or asynchronously. In normal operation, the counter is decremented by one count on each positive-going transition of the clock (CP). Counting is inhibited when the terminal enable input (\overline{TE}) is HIGH. The terminal count output (TC) goes LOW when the count reaches zero if TE is LOW, and remains LOW for one full clock period. When the synchronous preset enable input (PE) is LOW, data at the jam input (P0 to P7) is clocked into the counter on the next positive-going clock transition regardless of the state of TE. When the asynchronous preset enable input (PL) is LOW, data at the jam input (P0 to P7) is asynchronously forced into the counter regardless of the state of PE, TE, or CP. The jam inputs (P0 to P7) represent a single 8-bit binary word. When the master reset input (\overline{MR}) is LOW, the counter is asynchronously cleared to its maximum count (decimal 255) regardless of the state of any other input. If all control inputs except TE are HIGH at the time of zero count, the counters will jump to the maximum count, giving a counting sequence of 256 clock pulses long. Device may be cascaded using the TE input and the TC output, in either a synchronous or ripple mode. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. Features and benefits

- Cascadable
- Synchronous or asynchronous preset
- Low-power dissipation
- Complies with JEDEC standard no. 7A
- CMOS input levels
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from –40 °C to +80 °C and from –40 °C to +125 °C

3. Applications

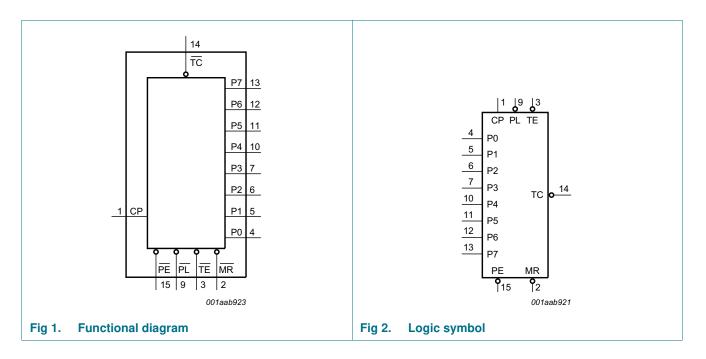
- Divide-by-n counters
- Programmable timers
- Interrupt timers
- Cycle/program counters.

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4. Ordering information

Table 1. Orderi	ng information			
Type number	Package			
	Temperature range	Name	Description	Version
74HC40103D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC40103PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

5. Functional diagram



Nexperia

74HC40103

8-bit synchronous binary down counter

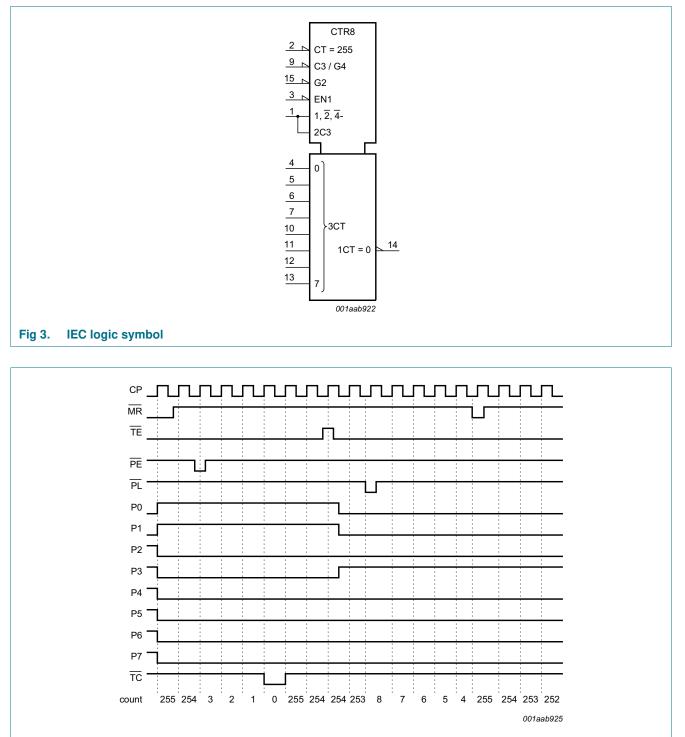
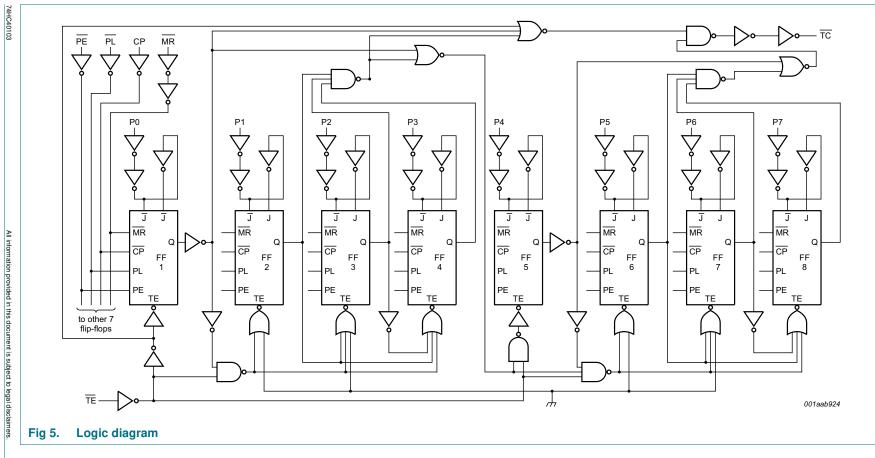


Fig 4. Timing diagram

74HC40103 Product data sheet Product data sheet



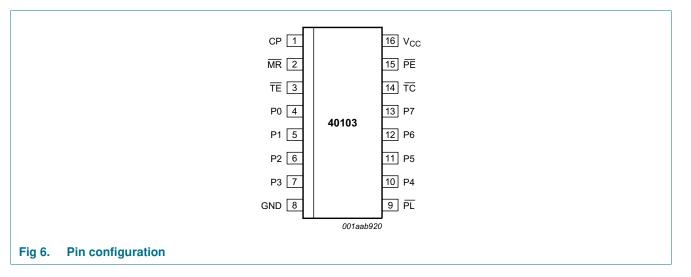


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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin o	description	
Symbol	Pin	Description
СР	1	clock input (LOW-to-HIGH, edge-triggered)
MR	2	asynchronous master reset input (active LOW)
TE	3	terminal enable input (active LOW)
P0	4	jam input 0
P1	5	jam input 1
P2	6	jam input 2
P3	7	jam input 3
GND	8	ground (0 V)
PL	9	asynchronous preset enable input (active LOW)
P4	10	jam input 4
P5	11	jam input 5
P5	12	jam input 6
P7	13	jam input 7
TC	14	terminal count output (active LOW)
PE	15	synchronous preset enable input (active LOW)
V _{CC}	16	positive supply voltage

7. Functional description

7.1 Function table

Table 3.Function table

Contro	ol inputs	i		Preset mode	Action ^[2]
MR	PL	PE	TE		
L	Х	Х	Х	asynchronous	clear to maximum count
Н	L	Х	Х	asynchronous	preset asynchronously
	Н	L	Х	synchronous	preset on next LOW-to HIGH clock transition
		Н	L	synchronous	count down
			Н	synchronous	inhibit counter

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

[2] Clock connected to CP.
 Synchronous operation: changes occur on the LOW-to-HIGH CP transition.
 Jam inputs: MSD = P7, LSD = P0.

8. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5$ V or $V_{I} > V_{CC} + 0.5$ V	[1]	-	±20	mA
I _{ОК}	output clamping current	$V_O < -0.5$ V or $V_O > V_{CC}$ + 0.5 V	[1]	-	±20	mA
lo	output current	$V_{O} = -0.5 \text{ V}$ to $V_{CC} + 0.5 \text{ V}$		-	±25	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	SO16 package	[2]	-	500	mW
		TSSOP16 packages	[3]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO16 package: above 70 °C, P_{tot} derates linearly with 8 mW/K.

[3] For TSSOP16 package: above 60 °C, P_{tot} derates linearly with 5.5 mW/K.

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9. Recommended operating conditions

Table 5.	Recommended operating con	ditions				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
$\Delta t / \Delta V$	input transition rise and	V _{CC} = 2.0 V	-	-	625	ns
	fall rates	$V_{CC} = 4.5 V$	-	1.67	139	ns
		$V_{CC} = 6.0 V$	-	-	83	ns
T _{amb}	ambient temperature		-40	-	+125	°C

10. Static characteristics

Table 6.Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		$V_{CC} = 4.5 V$	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ V$	4.4	4.5	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	V
		$I_{O} = 4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
l _l	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±0.1	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	μA
CI	input capacitance		-	3.5	-	pF

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Table 6. Static characteristics ... continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$T_{amb} = -40$) °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	-	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	-	-	V
		$I_{O} = -20 \ \mu A; V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	-	0.1	V
		$I_{O} = 4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.33	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	-	0.33	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±1.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μA
T _{amb} =40) °C to +125 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		$V_{CC} = 4.5 V$	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{\rm O} = -20 \ \mu \text{A}; \ V_{\rm CC} = 2.0 \ \text{V}$	1.9	-	-	V
		$I_{O} = -20 \ \mu A; V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{O} = -20 \ \mu A; V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_0 = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_0 = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V

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Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		$I_{O} = 4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
		$I_{\rm O} = 5.2 \text{ mA}; V_{\rm CC} = 6.0 \text{ V}$	-	-	0.4	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	160	μA

11. Dynamic characteristics

Table 7. Dynamic characteristics

 $GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF; see Figure 13.$

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					_
t _{pd}	propagation delay	CP to TC; see Figure 7 [1]				
		V _{CC} = 2.0 V	-	96	300	ns
		V _{CC} = 4.5 V	-	35	60	ns
		V _{CC} = 6.0 V	-	28	51	ns
		$V_{CC} = 5.0 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	30	-	ns
		TE to TC; see Figure 8				
		V _{CC} = 2.0 V	-	50	175	ns
		V _{CC} = 4.5 V	-	18	35	ns
		V _{CC} = 6.0 V	-	14	30	ns
		PL to TC; see Figure 9				
		V _{CC} = 2.0 V	-	102	315	ns
		V _{CC} = 4.5 V	-	37	63	ns
		V _{CC} = 6.0 V	-	30	53	ns
PHL	HIGH to LOW	MR to TC; see Figure 9				
	propagation delay	V _{CC} = 2.0 V	-	83	275	ns
		V _{CC} = 4.5 V	-	30	55	ns
		V _{CC} = 6.0 V	-	24	47	ns
t	transition time	see Figure 8 [2]				
		V _{CC} = 2.0 V	-	19	75	ns
		V _{CC} = 4.5 V	-	7	15	ns
		$V_{CC} = 6.0 V$	-	6	13	ns

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
W	pulse width	CP HIGH or LOW; see Figure 7				
		V _{CC} = 2.0 V	165	22	-	ns
		V _{CC} = 4.5 V	33	8	-	ns
		$V_{CC} = 6.0 V$	28	6	-	ns
		MR LOW; see Figure 9				
		V _{CC} = 2.0 V	125	39	-	ns
		V _{CC} = 4.5 V	25	14	-	ns
		V _{CC} = 6.0 V	21	11	-	ns
		PL LOW; see Figure 9				
		V _{CC} = 2.0 V	125	33	-	ns
		V _{CC} = 4.5 V	25	12	-	ns
		V _{CC} = 6.0 V	21	10	-	ns
rec	recovery time	MR to CP, PL to CP; see Figure 10				
		V _{CC} = 2.0 V	50	14	-	ns
		V _{CC} = 4.5 V	10	5	-	ns
		V _{CC} = 6.0 V	9	4	-	ns
t _{su}	set-up time	PE to CP; see Figure 11				
		V _{CC} = 2.0 V	75	22	-	ns
		V _{CC} = 4.5 V	15	8	-	ns
		V _{CC} = 6.0 V	13	6	-	ns
		TE to CP; see Figure 12				
		V _{CC} = 2.0 V	150	44	-	ns
		V _{CC} = 4.5 V	30	16	-	ns
		V _{CC} = 6.0 V	26	13	-	ns
		Pn to CP; see Figure 11				
		V _{CC} = 2.0 V	75	22	-	ns
		$V_{CC} = 4.5 V$	15	8	-	ns
		$V_{CC} = 6.0 V$	13	6	-	ns
h	hold time	PE to CP; see Figure 11				
		$V_{CC} = 2.0 V$	0	-14	-	ns
		$V_{CC} = 4.5 V$	0	-5	-	ns
		$V_{CC} = 6.0 V$	0	-4	-	ns
		TE to CP; see Figure 12				
		V _{CC} = 2.0 V	0	-30	-	ns
		V _{CC} = 4.5 V	0	-11	-	ns
		V _{CC} = 6.0 V	0	-9	-	ns
		Pn to CP; see Figure 11				
		V _{CC} = 2.0 V	0	-17	-	ns
		V _{CC} = 4.5 V	0	-6	-	ns
		$V_{CC} = 6.0 V$	0	-5	-	ns

Table 7. Dynamic characteristics ... continued CND OV(t) t 6 pair C 50 pE; app Eigure 12

8-bit synchronous binary down counter

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
f _{max}	maximum frequency	see Figure 7					
		V _{CC} = 2.0 V		3.0	10	-	MHz
		V _{CC} = 4.5 V		15	29	-	MHz
		V _{CC} = 6.0 V		18	35	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF		-	32	-	MHz
C _{PD}	power dissipation capacitance	$V_{I} = GND$ to V_{CC}	<u>[3]</u>	-	24	-	pF
$T_{amb} = -40$	0 °C to +85 °C						-
t _{pd}	propagation delay	CP to TC; see Figure 7	<u>[1]</u>				
		V _{CC} = 2.0 V		-	-	375	ns
		V _{CC} = 4.5 V		-	-	75	ns
		V _{CC} = 6.0 V		-	-	64	ns
		TE to TC; see Figure 8					
		V _{CC} = 2.0 V		-	-	220	ns
		V _{CC} = 4.5 V		-	-	44	ns
		V _{CC} = 6.0 V		-	-	37	ns
		PL to TC; see Figure 9					
		V _{CC} = 2.0 V		-	-	395	ns
		V _{CC} = 4.5 V		-	-	79	ns
		V _{CC} = 6.0 V		-	-	40	ns
t _{PHL}	HIGH to LOW propagation delay	MR to TC; see Figure 9					
		V _{CC} = 2.0 V		-	-	345	ns
		V _{CC} = 4.5 V		-	-	69	ns
		V _{CC} = 6.0 V		-	-	59	ns
t _t	transition time	see Figure 8	[2]				
		V _{CC} = 2.0 V		-	-	95	ns
		V _{CC} = 4.5 V		-	-	19	ns
		V _{CC} = 6.0 V		-	-	16	ns
tw	pulse width	CP HIGH or LOW; see Figure 7					
		V _{CC} = 2.0 V		205	-	-	ns
		V _{CC} = 4.5 V		41	-	-	ns
		V _{CC} = 6.0 V		35	-	-	ns
		MR LOW; see Figure 9					
		V _{CC} = 2.0 V		155	-	-	ns
		V _{CC} = 4.5 V		31	-	-	ns
		V _{CC} = 6.0 V		26	-	-	ns
		PL LOW; see Figure 9					
		V _{CC} = 2.0 V		155	-	-	ns
		V _{CC} = 4.5 V		31	-	-	ns
		$V_{\rm CC} = 6.0 \text{ V}$		26	-	-	ns

Table 7. Dynamic characteristics ... continued

8-bit synchronous binary down counter

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{rec}	recovery time	MR to CP, PL to CP; see Figure 10				
		V _{CC} = 2.0 V	65	-	-	ns
		V _{CC} = 4.5 V	13	-	-	ns
		V _{CC} = 6.0 V	11	-	-	ns
·su	set-up time	PE to CP; see Figure 11				
		V _{CC} = 2.0 V	95	-	-	ns
		V _{CC} = 4.5 V	19	-	-	ns
		V _{CC} = 6.0 V	16	-	-	ns
		TE to CP; see Figure 12				
		V _{CC} = 2.0 V	190	-	-	ns
		V _{CC} = 4.5 V	38	-	-	ns
		V _{CC} = 6.0 V	33	-	-	ns
		Pn to CP; see Figure 11				
		V _{CC} = 2.0 V	95	-	-	ns
		V _{CC} = 4.5 V	19	-	-	ns
		V _{CC} = 6.0 V	16	-	-	ns
ĥ	hold time	PE to CP; see Figure 11				
		V _{CC} = 2.0 V	0	-	-	ns
		V _{CC} = 4.5 V	0	-	-	ns
		V _{CC} = 6.0 V	0	-	-	ns
		TE to CP; see Figure 12				
		V _{CC} = 2.0 V	0	-	-	ns
		V _{CC} = 4.5 V	0	-	-	ns
		V _{CC} = 6.0 V	0	-	-	ns
		Pn to CP; see Figure 11				
		V _{CC} = 2.0 V	0	-	-	ns
		V _{CC} = 4.5 V	0	-	-	ns
		V _{CC} = 6.0 V	0	-	-	ns
max	maximum frequency	see Figure 7				
		V _{CC} = 2.0 V	2.4	-	-	MHz
		$V_{CC} = 4.5 V$	12	-	-	MHz
		V _{CC} = 6.0 V	14	-	-	MHz

Table 7. Dynamic characteristics ... continued GND = 0 V: $t_r = t_r = 6$ ns: $C_1 = 50$ pF: see Figure 13

8-bit synchronous binary down counter

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Γ _{amb} = -40	0 °C to +125 °C					
t _{pd}	propagation delay	CP to TC; see Figure 7	[1]			
		V _{CC} = 2.0 V	-	-	450	ns
		V _{CC} = 4.5 V	-	-	90	ns
		V _{CC} = 6.0 V	-	-	77	ns
		TE to TC; see Figure 8				
		V _{CC} = 2.0 V	-	-	265	ns
		V _{CC} = 4.5 V	-	-	53	ns
		V _{CC} = 6.0 V	-	-	45	ns
		PL to TC; see Figure 9				
		V _{CC} = 2.0 V	-	-	475	ns
		$V_{CC} = 4.5 V$	-	-	95	ns
		$V_{CC} = 6.0 V$	-	-	81	ns
t _{PHL}	HIGH to LOW	MR to TC; see Figure 9				
	propagation delay	V _{CC} = 2.0 V	-	-	415	ns
		V _{CC} = 4.5 V	-	-	83	ns
		$V_{CC} = 6.0 V$	-	-	71	ns
t _t	transition time		[2]			
		$V_{\rm CC} = 2.0 \rm V$	-	-	110	ns
		V _{CC} = 4.5 V	-	-	22	ns
		$V_{CC} = 6.0 V$	-	-	19	ns
tw	pulse width	CP HIGH or LOW; see Figure 7				
		V _{CC} = 2.0 V	250	-	-	ns
		V _{CC} = 4.5 V	50	-	-	ns
		$V_{CC} = 6.0 V$	43	-	-	ns
		MR LOW; see Figure 9				
		V _{CC} = 2.0 V	190	-	-	ns
		V _{CC} = 4.5 V	38	-	-	ns
		$V_{\rm CC} = 6.0 \rm V$	32	-	-	ns
		PL LOW; see Figure 9				
		V _{CC} = 2.0 V	190	-	-	ns
		$V_{CC} = 4.5 V$	38	-	-	ns
		$V_{\rm CC} = 6.0 \text{ V}$	32	-	-	ns
t _{rec}	recovery time	MR to CP, PL to CP; see Figure 10				
160	-	V _{CC} = 2.0 V	75	_	-	ns
		$V_{CC} = 4.5 V$	15	-	-	ns

Table 7. Dynamic characteristics ... continued CND OV(t) t 6 pair C 50 pEr app Eigure 12

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{su}	set-up time	PE to CP; see Figure 11				
		V _{CC} = 2.0 V	110	-	-	ns
		V _{CC} = 4.5 V	22	-	-	ns
		V _{CC} = 6.0 V	19	-	-	ns
		TE to CP; see Figure 12				
		V _{CC} = 2.0 V	225	-	-	ns
		$V_{CC} = 4.5 V$	45	-	-	ns
		V _{CC} = 6.0 V	38	-	-	ns
		Pn to CP; see Figure 11				
		V _{CC} = 2.0 V	110	-	-	ns
		V _{CC} = 4.5 V	22	-	-	ns
		V _{CC} = 6.0 V	19	-	-	ns
t _h	hold time	PE to CP; see Figure 11				
		V _{CC} = 2.0 V	0	-	-	ns
		$V_{CC} = 4.5 V$	0	-	-	ns
		V _{CC} = 6.0 V	0	-	-	ns
		TE to CP; see Figure 12				
		V _{CC} = 2.0 V	0	-	-	ns
		V _{CC} = 4.5 V	0	-	-	ns
		V _{CC} = 6.0 V	0	-	-	ns
		Pn to CP; see Figure 11				
		V _{CC} = 2.0 V	0	-	-	ns
		$V_{CC} = 4.5 V$	0	-	-	ns
		V _{CC} = 6.0 V	0	-	-	ns
f _{max}	maximum frequency	see <u>Figure 7</u>				
		V _{CC} = 2.0 V	2.0	-	-	MHz
		V _{CC} = 4.5 V	10	-	-	MHz
		$V_{\rm CC} = 6.0 \ V$	12	-	-	MHz

Table 7. Dynamic characteristics ... continued GND = 0 V: $t = t_r = 6$ ps: $C_r = 50$ pE: see Figure 13

 $\label{eq:tpd} [1] \quad t_{pd} \mbox{ is the same as } t_{PHL}, \mbox{ } t_{PLH}.$

 $\label{eq:CPD} [3] \quad C_{\text{PD}} \text{ is used to determine the dynamic power dissipation } (\text{P}_{\text{D}} \text{ in } \mu\text{W}).$

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}^{2} \times f_{o})$ where:

 $f_i = input frequency in MHz;$

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

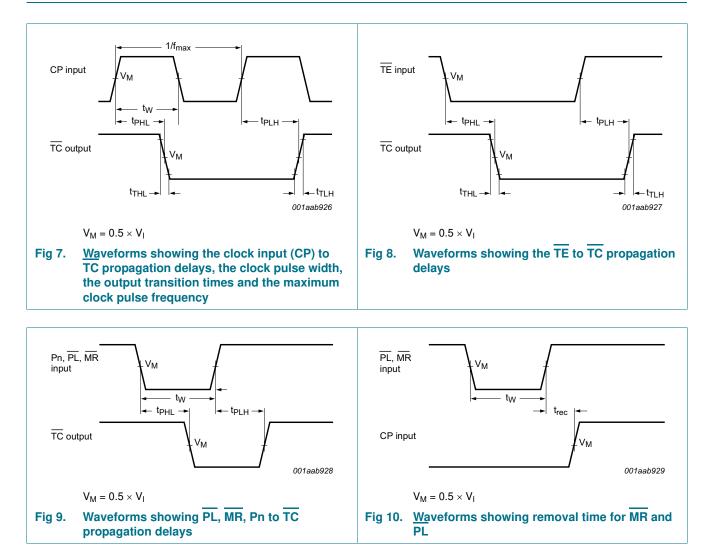
 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}{}^2 \times f_o)$ = sum of outputs.

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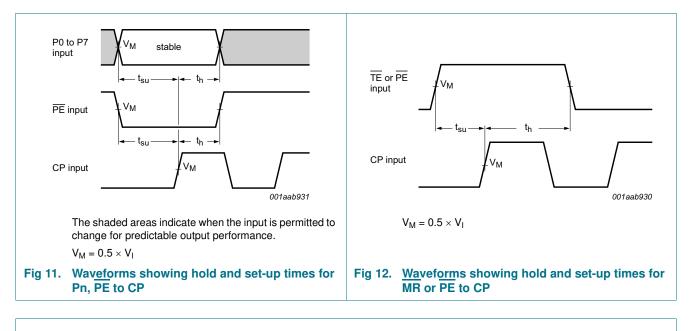
12. Waveforms

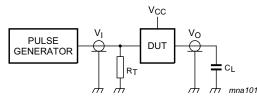


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Test data is given in Table 8.

Definitions for test circuit:

 R_{T} = Termination resistance should be equal to output impedance Z_{o} of the pulse generator.

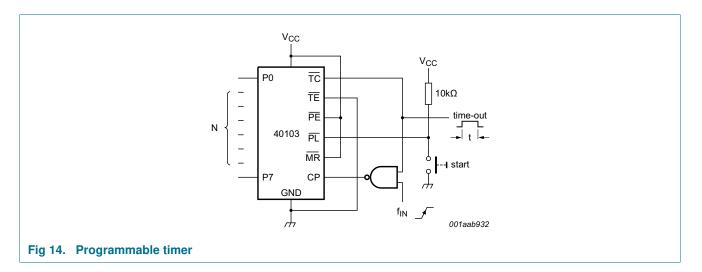
 C_L = Load capacitance including jig and probe capacitance.

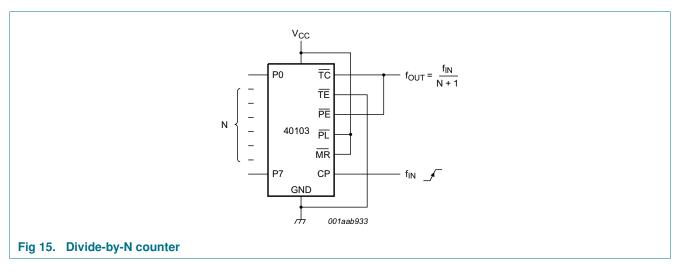
Fig 13. Test circuit for measuring switching times

Table 8. Test data				
Supply	Input		Load	
V _{CC}	VI	t _r , t _f	CL	
2.0 V	V _{CC}	6 ns	50 pF	
4.5 V	V _{CC}	6 ns	50 pF	
6.0 V	V _{CC}	6 ns	50 pF	
5.0 V	V _{CC}	6 ns	15 pF	

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13. Application information





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14. Package outline

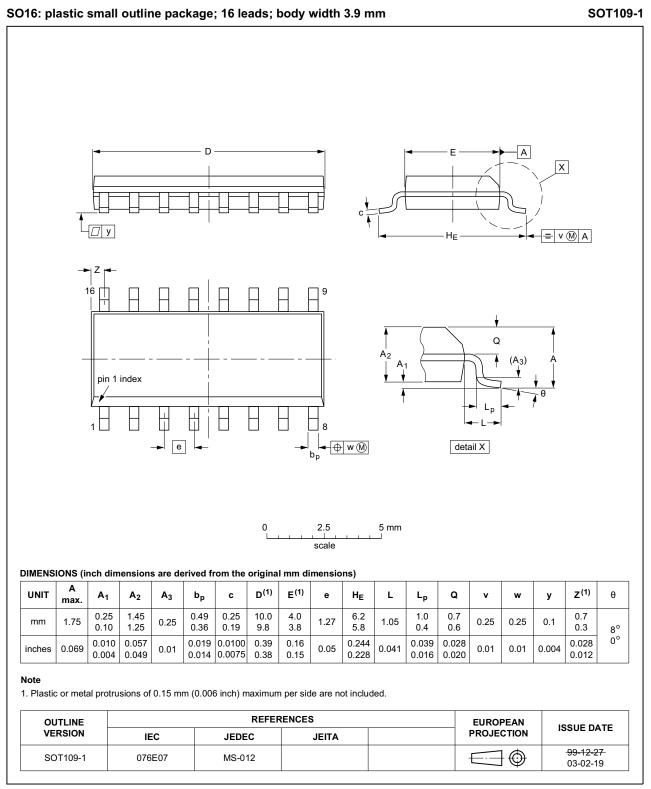


Fig 16. Package outline SOT109-1 (SO16)

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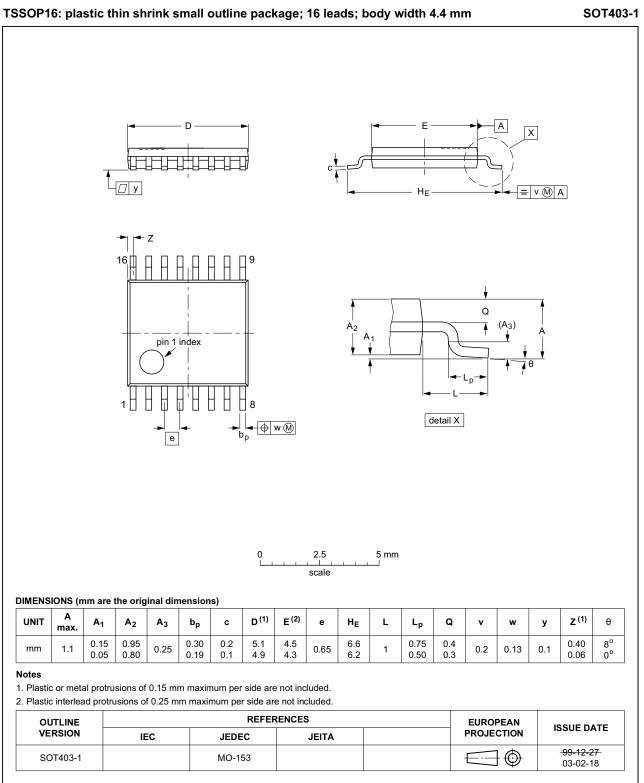


Fig 17. Package outline SOT403-1 (TSSOP16)

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15. Abbreviations

Table 9. Abbreviations			
Acronym	Description		
CMOS	Complementary Metal Oxide Semiconductor		
DUT	Device Under Test		
ESD	ElectroStatic Discharge		
НВМ	Human Body Model		
MM	Machine Model		

16. Revision history

Table 10.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC40103 v.5	20160421	Product data sheet	-	74HC40103 v.4	
Modifications:	Type number 74HC40103DB (SOT338-1) removed.				
74HC40103 v.4	20160127	Product data sheet	-	74HC40103 v.3	
Modifications:	Type number 74HC40103N (SOT38-4) removed.				
74HC40103 v.3	20041112	Product data sheet	-	74HC_HCT40103_CNV v.2	
Modifications:	• The format of this data sheet has been redesigned to comply with the current presentation and information standard of Philips Semiconductors.				
	 Removed type number 74HCT40103. 				
	Inserted family specification.				
74HC_HCT40103_CNV v.2	19970918	Product specification	-	74HC_HCT40103 v.1	
74HC_HCT40103 v.1	19901201	Product specification	-	-	

17. Legal information

17.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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